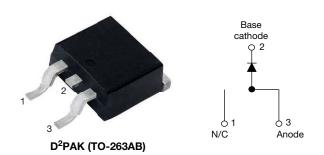


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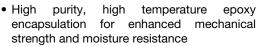
High Performance Schottky Rectifier, 15 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	15 A						
V _R	35 V, 40 V, 45 V						
V _F at I _F	0.50 V						
I _{RM} typ.	70 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	16 mJ						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- 150 °C T_J operation
- · Very low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-12TQ...S-M3 Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	15	Α					
V _{RRM}	Range	35 to 45	V					
I _{FSM}	$t_p = 5 \mu s sine$	990	Α					
V _F	15 A _{pk} , T _J = 125 °C	0.50	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-12TQ035S-M3	VS-12TQ040S-M3	VS-12TQ045S-M3	UNITS			
Maximum DC reverse voltage	V_R	35	40	45	W			
Maximum working peak reverse voltage	V _{RWM}	33	40	45	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 120 °C	15	Α				
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated	990	А			
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	250				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2.4 A, L = 5.5 mH		16	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		2.4	А			

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST C	TEST CONDITIONS				
		15 A	T _{.1} = 25 °C	0.56			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	30 A	TJ=25 C	0.71	V		
See fig. 1	VFM ('')	15 A	T _{.1} = 125 °C	0.50	v		
		30 A	TJ = 125 C	0.64			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm R}$ = Rated $V_{\rm R}$	1.75	mA		
Maximum reverse leakage current		T _J = 125 °C	V _R = nateu v _R	110			
Typical reverse leakage current	I _{RM} ⁽¹⁾	$T_J = 125 ^{\circ}\text{C}$ $V_R = \text{Rated } V_R$		70	mA		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		900	pF		
Typical series inductance	L _S	Measured lead to lead 5	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C			
Maximum thermal resistant junction to case	ance,	R _{thJC}	DC operation See fig. 4	2.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV			
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf·in)			
Marking device			Case style D ² PAK (TO-263AB)	12TQ030S 12TQ044S 12TQ045S				

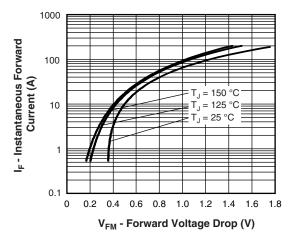


Fig. 1 - Maximum Forward Voltage Drop Characteristics

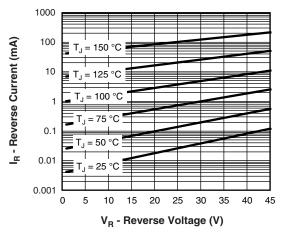


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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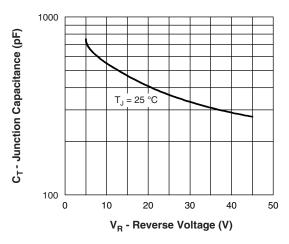


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

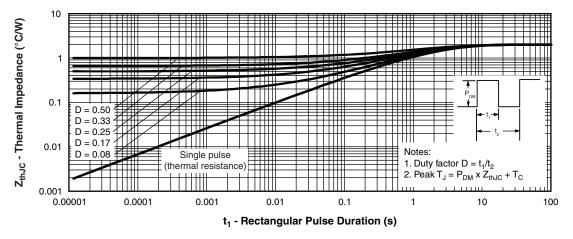


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

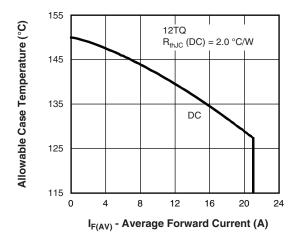


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

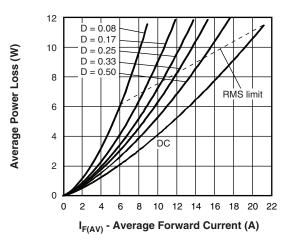


Fig. 6 - Forward Power Loss Characteristics

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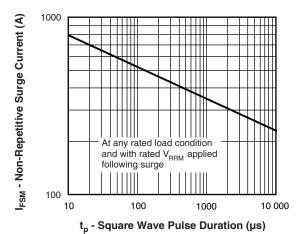


Fig. 7 - Maximum Non-Repetitive Surge Current

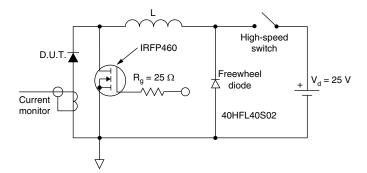
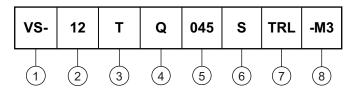


Fig. 8 - Unclamped Inductive Test Circuit

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating

3 - Package: T = TO-220

4 - Schottky "Q" series 035 = 35 V

5 - Voltage ratings — 040 = 40 V 6 - S = D²PAK (TO-263AB) 045 = 45 V

7 - • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-12TQ035S-M3	50	Antistatic plastic tubes						
VS-12TQ035STRL-M3	800	13" diameter plastic tape and reel						
VS-12TQ035STRR-M3	800	13" diameter plastic tape and reel						
VS-12TQ040S-M3	50	Antistatic plastic tubes						
VS-12TQ040STRL-M3	800	13" diameter plastic tape and reel						
VS-12TQ040STRR-M3	800	13" diameter plastic tape and reel						
VS-12TQ045S-M3	50	Antistatic plastic tubes						
VS-12TQ045STRL-M3	800	13" diameter plastic tape and reel						
VS-12TQ045STRR-M3	800	13" diameter plastic tape and reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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